

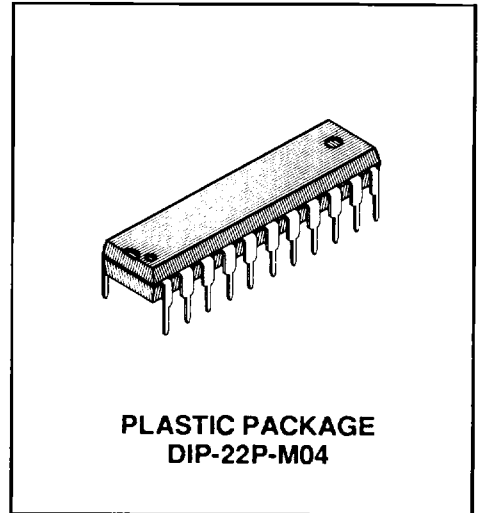
# MB40578/40578-7

## 1 CHANNEL 8-BIT VIDEO A/D CONVERTER

### 1 CHANNEL 8-BIT VIDEO A/D CONVERTER (20MSPS)

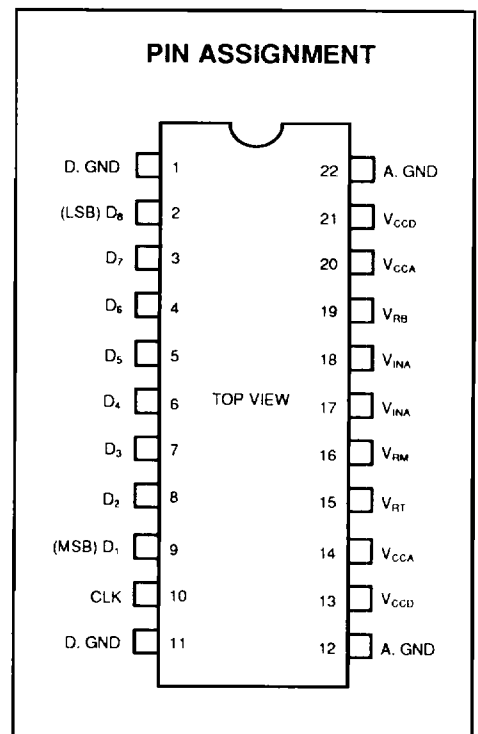
The Fujitsu MB40578 is a low power ultra-high speed video A/D converter fabricated with Fujitsu Advanced Bipolar Technology. The MB40578 also adopts the fully-parallel comparison technique (flash method) for high speed conversion and can convert wide band analog signal such as video signal to digital signal at a sampling rate of DC through 20 Mega-samples/sec. Because of such high-speed operation, the MB40578 is suitable for digital video applications such as the digital TV, video processing with computer, or radar signal processing.

- Resolution: 8 bits
- Linearity Error:  $\pm 0.2\%$  max. (MB40578)  
 $\pm 0.4\%$  max. (MB40578-7)
- Maximum conversion Rate: 20 MSPS min.
- Analog Input Voltage: 3.0V to 5.0V
- Digital I/O level: TTL compatible
- Single power supply: +5V
- Power Dissipation: 480mW typ.
- Package: Standard 22-pin DIP Package: Suffix: -P



### ABSOLUTE MAXIMUM RATINGS (See NOTE)

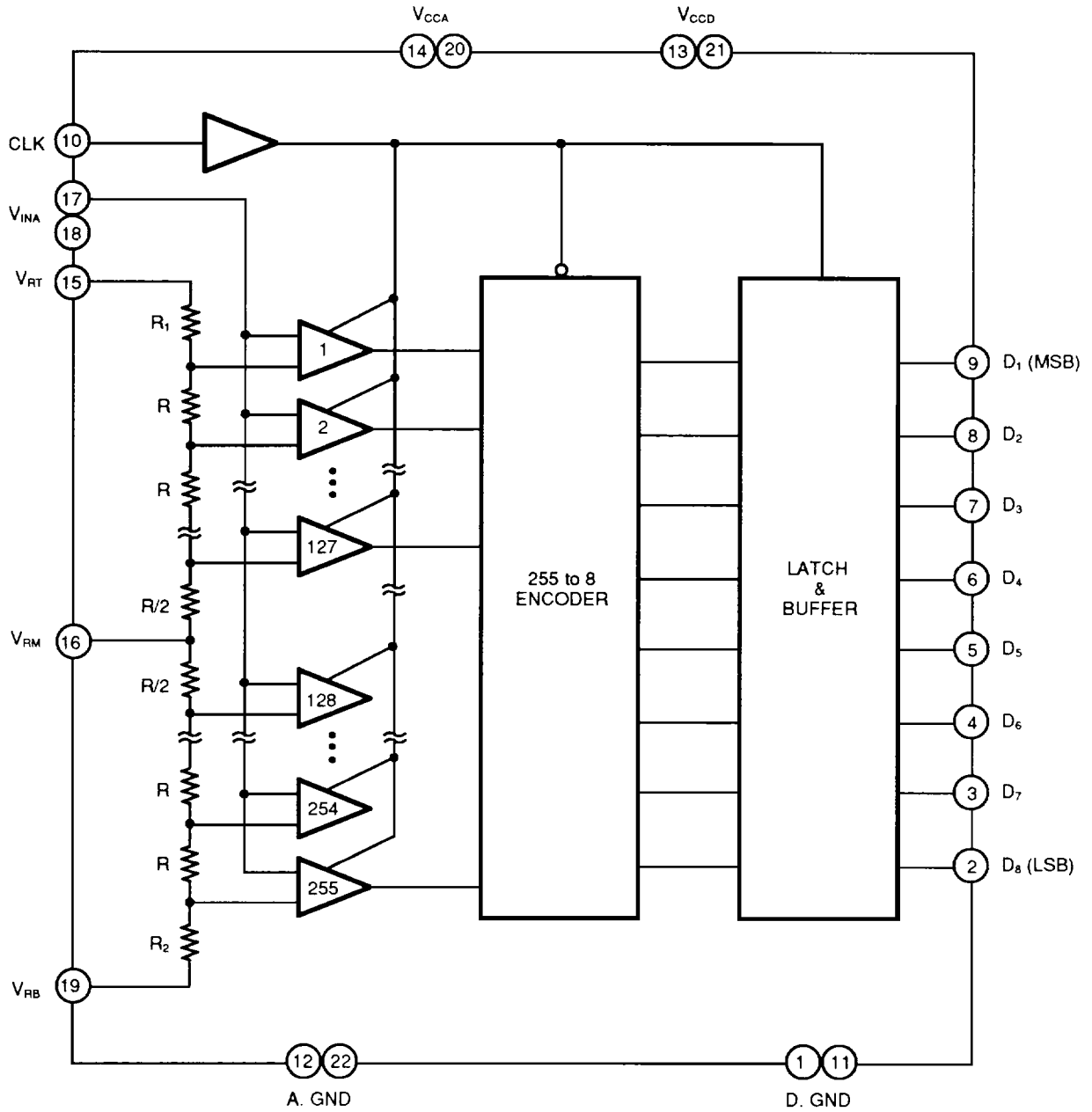
Rating	Symbol	Value	Unit
Power Supply Voltage	$V_{CCA}$ $V_{CCD}$	-0.5 to +7.0	V
Digital Input Voltage	$V_{IND}$	-0.5 to +7.0	V
Analog Input Voltage	$V_{INA}$	-0.5 to $V_{CC} + 0.5$	V
Analog Reference Voltage	$V_{RT}, V_{RB}$	-0.5 to $V_{CC} + 0.5$	V
Storage Temperature	$T_{STG}$	-55 to +125	°C



**NOTE:** Permanent device damage may occur if the above **Absolute Maximum Ratings** are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

Fig. 1 – MB40578 BLOCK DIAGRAM



## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Power Supply Voltage *1	$V_{CCA}$ $V_{CCD}$	4.75	5.00	5.25	V
Analog Input Voltage *2	$V_{INA}$	3		5	V
Analog Reference Voltage (Top Side) *2	$V_{RT}$		5	5.1	V
Analog Reference Voltage (Bottom Side) *2	$V_{RB}$	2.9	3		V
Digital High-level Output Current	$I_{OHD}$	-400			$\mu$ A
Digital Low-level Output Current	$I_{OLD}$			4	mA
Clock Pulse Width at High Level	$t_{W+}$	25			ns
Clock Pulse Width at Low Level	$t_{W-}$	25			ns
Operating Temperature	$T_A$	0		70	$^{\circ}$ C

**Note** \*1: Please keep  $V_{CCA}$  and  $V_{CCD}$  at the same potential.

\*2:  $V_{RB} < V_{INA} < V_{RT}$ ,  $V_{RT} - V_{RB} = 2V + 0.1V$ .

## ELECTRICAL CHARACTERISTICS

### ANALOG DC CHARACTERISTICS

(V<sub>CC</sub> = 4.75 to 5.25V, T<sub>A</sub> = 0 to 70°C)

Parameter	Symbol	Condition	Value			Unit	
			Min	Typ	Max		
Resolution					8	bits	
Linearity Error	MB40578	LE	DC			±0.2	%
	MB40578-8					±0.4	
Equivalent Analog Input Resistance	R <sub>INA</sub>		50			kΩ	
Analog Input Capacitance	C <sub>INA</sub>			120	230	pF	
Analog High-Level Input Current	I <sub>IHA</sub>				150	μA	
Analog Low-Level Input Current	I <sub>ILA</sub>				145	μA	
Reference Current	I <sub>RB</sub>	V <sub>RT</sub> = 5V V <sub>RB</sub> = 3V	-15	-9		mA	

### DIGITAL DC CHARACTERISTICS

(V<sub>CC</sub> = 4.75 to 5.25V, T<sub>A</sub> = 0 to 70°C)

Parameter	Symbol	Condition	Value			Unit
			Min	Typ	Max	
High-Level Output Volotage	V <sub>OHD</sub>	I <sub>OH</sub> = -400μA	2.7			V
Low-Level Output Volotage	V <sub>OLD</sub>	I <sub>OL</sub> = 1.6mA			0.4	V
High-Level Input Volotage	V <sub>IHD</sub>		2			V
Low-Level Input Volotage	V <sub>ILD</sub>				0.8	V
Maximum Input Current	I <sub>ID</sub>	V <sub>ID</sub> = 7V			100	μA
High-Level Input Current	I <sub>IHD</sub>	V <sub>IHD</sub> = 2.7V		0	20	μA
Low-Level Input Current	I <sub>ILD</sub>	V <sub>ILD</sub> = 0.4V	-400	-40		μA
Power Supply Current	I <sub>CC</sub>			92	160	mA

# ELECTRICAL CHARACTERISTICS (Continued)

## SWITCHING CHARACTERISTICS

( $V_{CC} = 5V, T_A = 25^\circ C$ )

Parameter	Symbol	Condition	Value			Unit
			Min	Typ	Max	
Maximum Conversion Rate	FS		20	30		MSPS
Digital Output Delay Time	tpd		5	15	40	ns

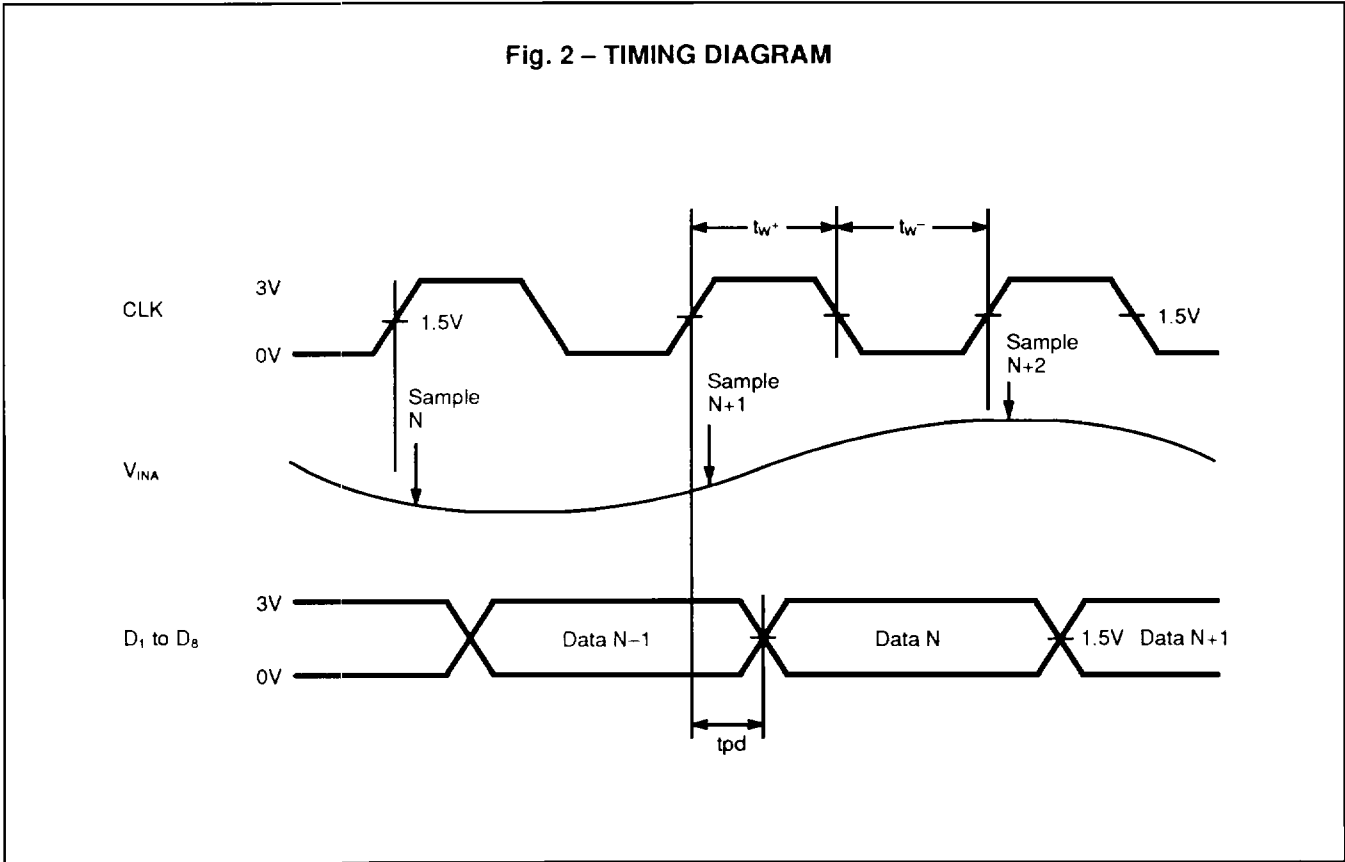
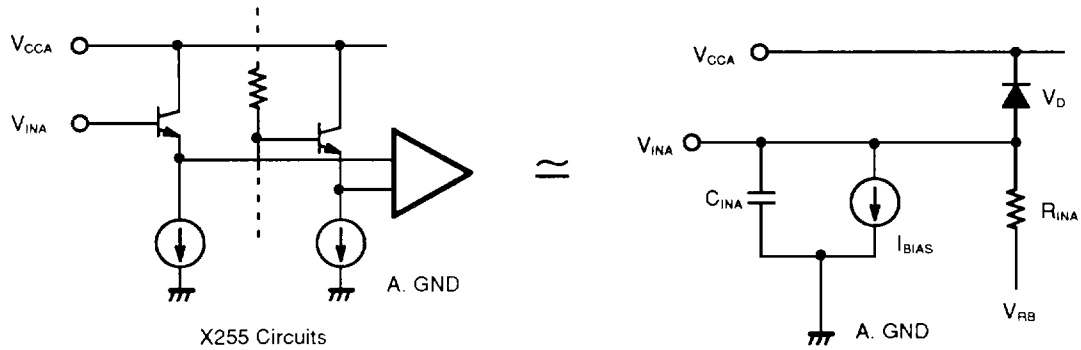


Fig. 3 – ANALOG INPUT EQUIVALENT CIRCUIT



- $C_{INA}$ : Non-linear Emitter-follower Junction Capacitance
- $R_{INA}$ : Linear Resistance Model for Input Current Transition by Comparator Switching:  
Infinite value for  $V_{IN} < V_{RB}$  or when CLK = High
- $V_{RB}$ : Voltage at  $V_{RB}$  terminal.
- $I_{BIAS}$ : Constant Input Bias Current
- $V_D$ : The base-collector junction diode of emitter-follower transistor.

Fig. 4 – DIGITAL INPUT EQUIVALENT

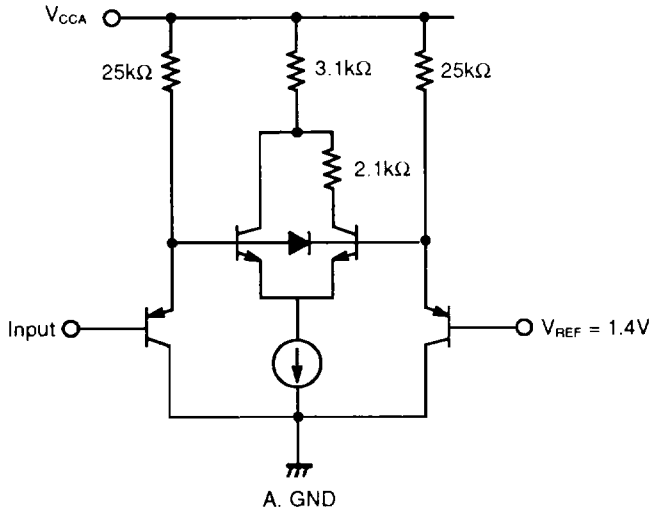
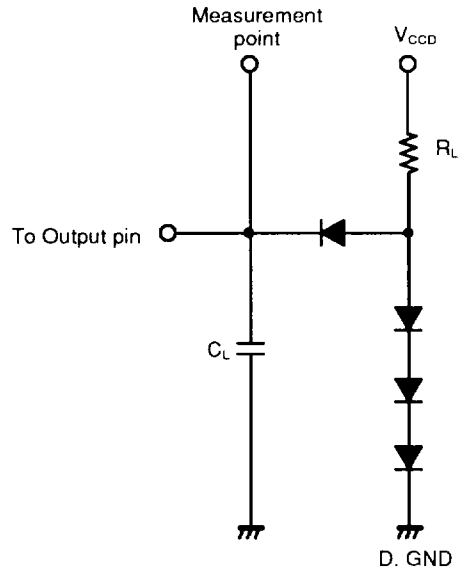


Fig. 5 – LOAD CIRCUIT FOR OUTPUT BUFFER



**Note**  $R_L = 2k\Omega$   
 $C_L = 15pF$  including scope and jig capacitance  
 Diodes: IN3064 or equivalent

OUTPUT CODE

( $V_{CC} = 5.0V$ ,  $V_{RT} \cong 5.0V$ ,  $V_{RB} \cong 3.0V$ )

Step	Analog Input Voltage	Digital Output Code
0	2.960V	00000000
1	2.968V	00000001
.	.	.
.	.	.
127	3.976V	01111111
128	3.984V	10000000
129	3.992V	10000001
.	.	.
.	.	.
245	4.992V	11111110
255	5.000V	11111111

Note: Adjust  $V_{ZT} = 2.964V$  and  $V_{FT} = 4.996V$  with  $V_{RT}$  and  $V_{RB}$ . The Analog Input Voltage are the center values of each step.

Fig. 6 – IDEAL CONVERSION CHARACTERISTICS

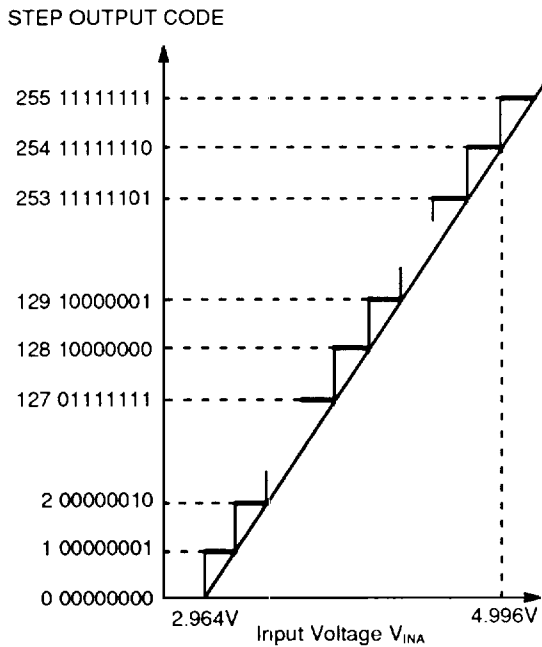
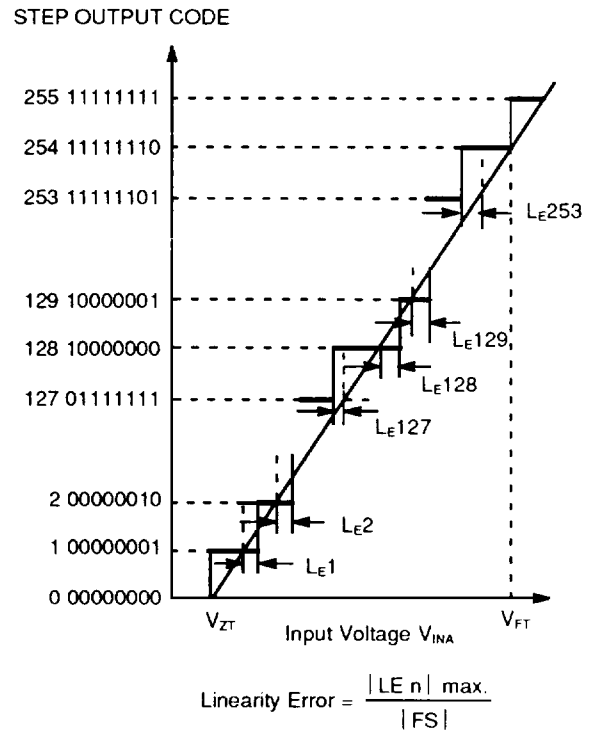
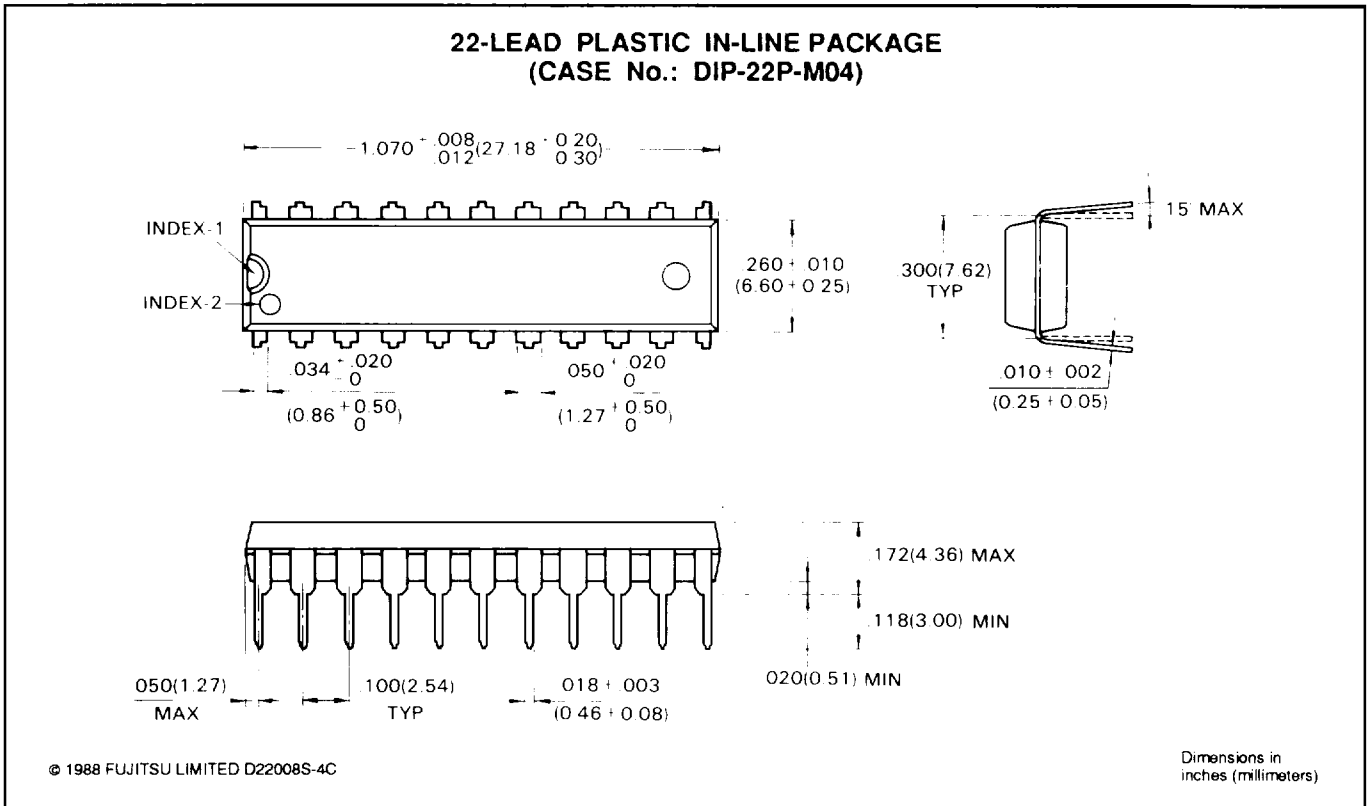


Fig. 7 – PRACTICAL CONVERSION CHARACTERISTICS



## PACKAGE DIMENSIONS



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